

6-Unit 150mA Transistor Array

IR2425

T-52-13-45

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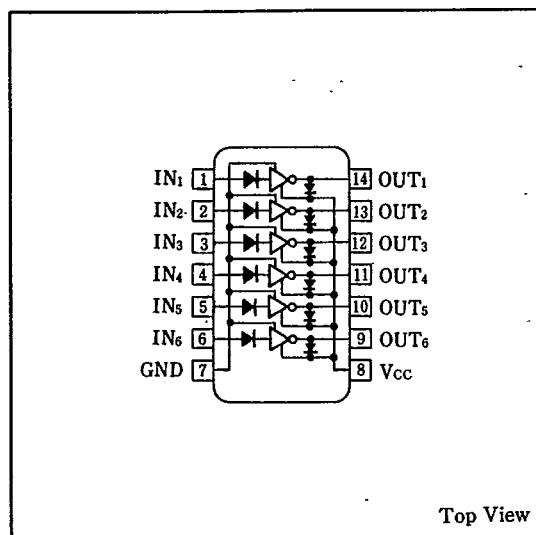
■ Description

The IR2425 is a 6-circuit driver. The internal clamping diodes enable the IC to drive the inductive load directly.

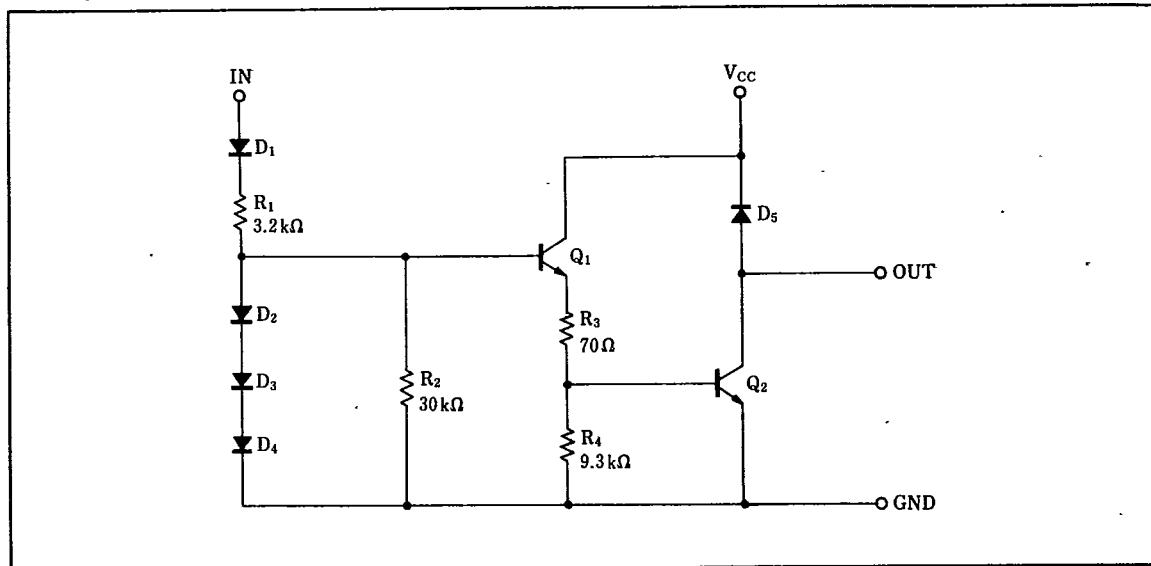
■ Features

1. Internal negative input voltage protective diode
2. Low output saturation voltage
3. Internal output clamping diode
4. 14-pin dual-in-line package

■ Pin Connections



■ Equivalent Circuit



SHARP

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Absolute Maximum Ratings

Parameter	Symbol	Condition	Rating	Unit
Supply voltage	V _{CC}		15	V
Breakdown voltage between collector-emitter	BV _{CEO}		18	V
Output current	I _{OUT}	Each circuit	150	mA
Clamp diode surge current	I _{surge}		150	mA
Input voltage	V _{IN}		-35~V _{CC}	V
Power dissipation	P _D	T _a ≤25°C	650	mW
P _D derating ratio	ΔP _D /°C	T _a >25°C	6.5	mW/°C
Operating temperature	T _{opr}		-10~+65	°C
Storage temperature	T _{stg}		-25~+100	°C

**Electrical Characteristics**(V_{CC}=15V, T_a=-10~+65°C)

Parameter	Symbol	Condition	MIN.	TYP.	MAX.	Unit
No-load circuit current	I _{CC}	Total amount of current flowing through one circuit when V _{CC} =V _{IN} =15V and V _{OUT} =0V		12	22	mA
On-state input current	I _{I ON}	V _{IN} =3.5V, V _{OUT} =0V		0.3	1.2	mA
		V _{IN} =8V, V _{OUT} =0V		2.0	5.5	
ON-state output voltage	V _{O ON}	V _{IN} =3.5V, I _{OUT} =130mA			0.8	V
OFF-state output current	I _{O OFF}	I _{IN} =12 μA, V _{OUT} =15V			100	μA
Input reverse leakage current	I _{IR}	V _{IN} =-30V, V _{OUT} =0V			10	μA
Clamp diode forward voltage	V _F	I _F =130mA			2.0	V
Clamp diode reverse current	I _R	V _R =15V			100	μA

Electrical Characteristic Curve**Output current—Duty cycle Characteristics**